

SANYO**LA4581MB****Preamplifier + Power Amplifier
for 3V Headphone Stereos****Overview**

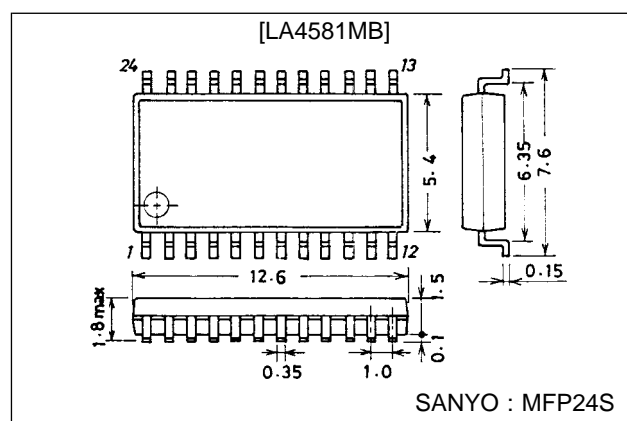
The LA4581MB is an auto reverse-supported preamplifier + power amplifier IC that is intended for use in 3V headphone stereos.

Features

- Preamplifier muting and preamplifier output on/off can be implemented with one pin. This IC can easily be used to construct a set with a radio.
- The power amplifier needs no input/output coupling capacitor.
- A high-frequency cut capacitor is connected to the preamplifier input pin and the power amplifier input pin. (Anti-buzz provision)
- Because V_{ref} AMP ($r_0 = 10\ \Omega$) is built in, the virtual grounding impedance is about $10\ \Omega$. This eliminates the need for a large capacitor.
- $8\ \Omega$ speaker drivable.

Package Dimensions

unit : mm

3112-MFP24S**Specifications****Maximum Ratings at $T_a = 25\ ^\circ\text{C}$**

Parameter	Symbol	Conditions	Ratings	Unit
Maximum supply voltage	$V_{CC\ max}$		4.5	V
Allowable power dissipation	$P_d\ max$		530	mW
Operating temperature	T_{opr}		-20 to +75	$^\circ\text{C}$
Storage temperature	T_{stg}		-40 to +125	$^\circ\text{C}$

Operating Conditions at $T_a = 25\ ^\circ\text{C}$

Parameter	Symbol	Conditions	Ratings	Unit
Recommended supply voltage	V_{CC}		3.0	V
Operating supply voltage range	$V_{CC\ op}$		1.8 to 3.6	V

**Operating Characteristics at $T_a = 25\ ^\circ\text{C}$, $V_{CC} = 3.0\ \text{V}$, $f = 1\ \text{kHz}$, $0.775\ \text{V} = 0\ \text{dBm}$,
 $R_L = 10\ \text{k}\Omega$ (preamplifier), $R_L = 16\ \Omega$ (power amplifier)**

Parameter	Symbol	Output	min	typ	max	Unit
[Pre + Power]						
Quiescent current	I_{CCO}	$R_g = 2.2\ \text{k}\Omega$ (preamplifier) $V_{IN} = 0\ \text{V}$		17	27	mA
Voltage gain (Closed)	V_{GT}	$V_O = -5\ \text{dBm}$	65	68	71	dB

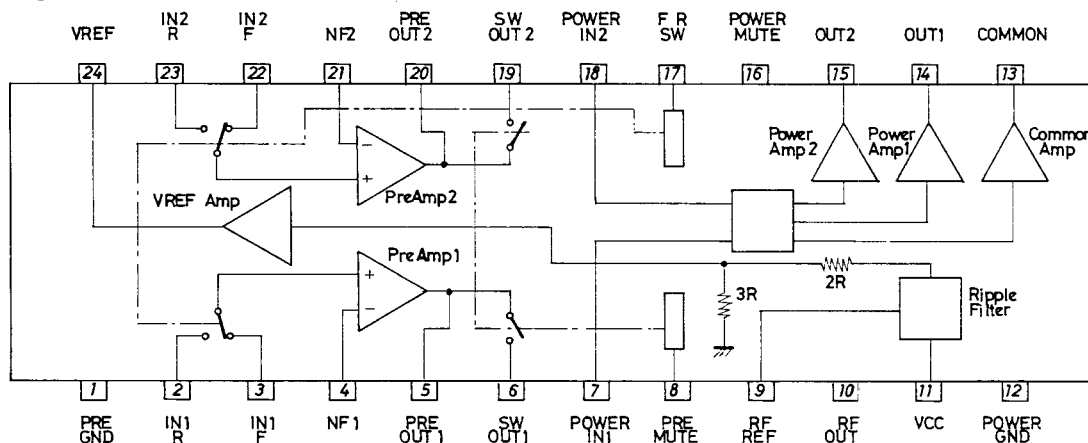
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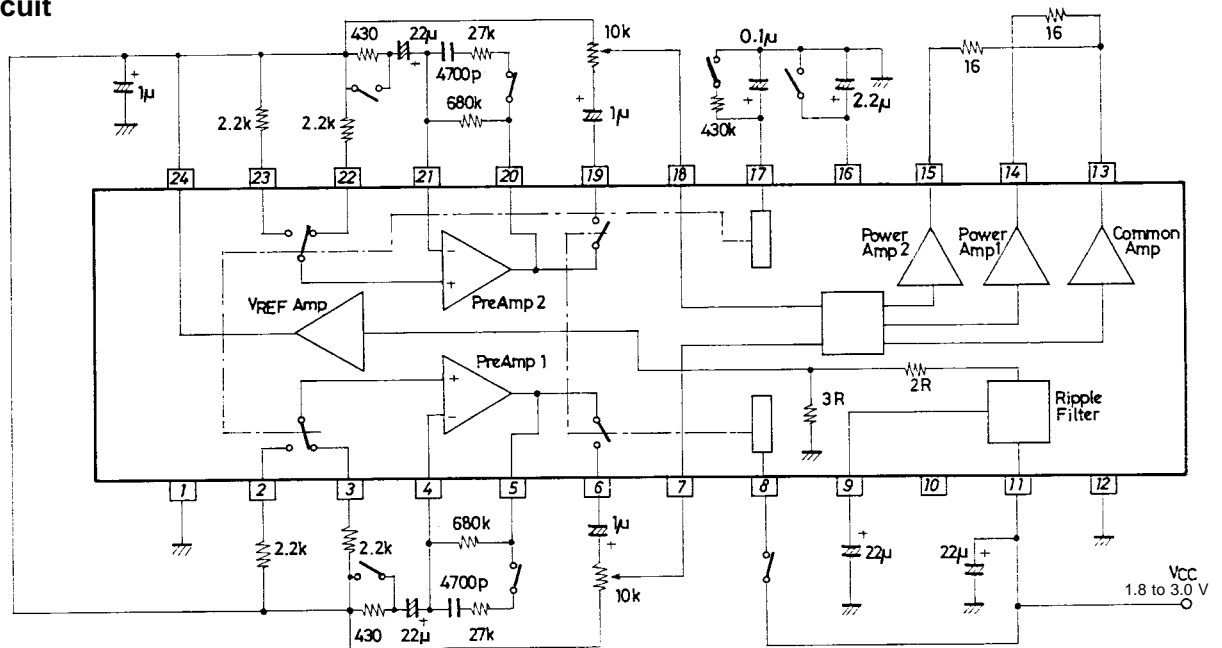
Parameter	Symbol	Output	min	typ	max	Unit
[Preamplifier]						
Voltage gain (Open)	VGo	$V_O = -5 \text{ dBm}$	70	80		dB
Voltage gain (Closed)	VG1	$V_O = -5 \text{ dBm}$		40		dB
Maximum output voltage	V_{Omax}	THD = 1 %, $V_{CC} = 1.8 \text{ V}$	0.1	0.2		V
Total harmonic distortion	THD1	$V_O = 0.2 \text{ V}$, $V_G = 40 \text{ dB/NAB}$		0.05	0.5	%
Equivalent input noise voltage	V_{N1}	$R_g = 2.2 \text{ k}\Omega$, B.P.F = 20 to 20 kHz		1.3	2.0	μV
Crosstalk	CT1	$R_g = 2.2 \text{ k}\Omega$, TUNE 1 kHz	60	80		dB
Ripple rejection ratio	R_{r1}	$R_g = 2.2 \text{ k}\Omega$, $V_{CC} = 1.8 \text{ V}$, $V_r = -20 \text{ dBm}$, $f = 100 \text{ Hz}$	40	50		dB
[Power Amplifier]						
Output voltage	P_O	THD = 10%	23	32		mW
Voltage gain (Closed)	VG2	$V_O = -5 \text{ dBm}$	25	28	31	dB
Total harmonic distortion	THD2	$P_O = 1 \text{ mW}$		0.4	1.0	%
Interchannel crosstalk	CT_T	$V_O = -5 \text{ dBm}$, $R_v = 0 \Omega$	30	40		dB
Output noise voltage	V_{NO}	$R_g = 0$, B.P.F = 20 to 20 kHz		24	40	μV
Ripple rejection ratio	R_{r2}	$R_g = 0$, $V_r = -20 \text{ dB}$, $f = 100 \text{ Hz}$, $V_{CC} = 1.8 \text{ V}$	45	60		dB
Input resistance	R_{IN}		22	30	38	$\text{k}\Omega$
DC offset voltage	V_{ODCoff}	Between 13-14 and 15	-90		+90	mV

Note) Power amplifier voltage gain VG2 increases by about 1 dB for min/max respectively than specified above when $R_L = 32 \Omega$.

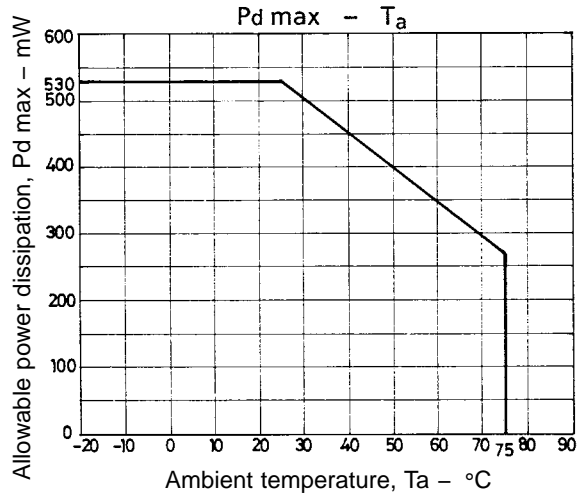
Block Diagram



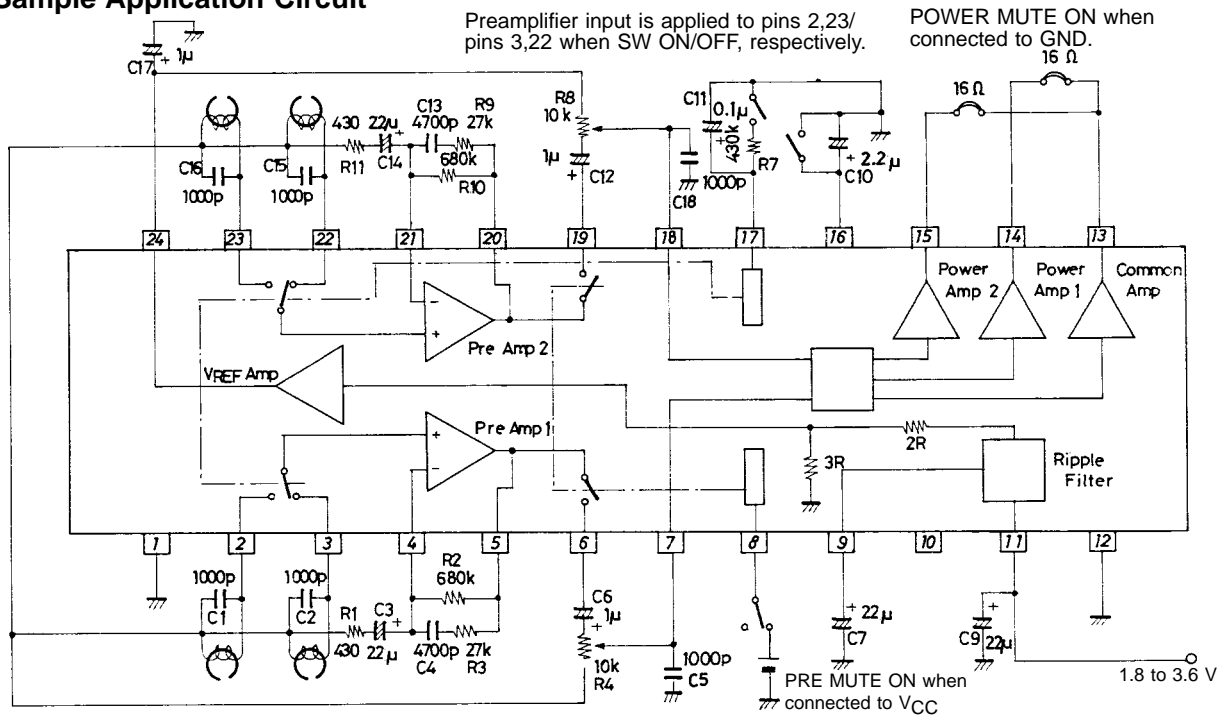
Test Circuit



Unit (resistance: Ω , capacitance: F)



Sample Application Circuit



Note) Pre closed loop gain VG = 40 dB/1 kHz NAB

Unit (resistance: Ω, capacitance: F)

Pin and external part functions (when the voltage is V_{CC} = 3.0 V)

Pin No.	Pin Function
1	PRE GND
2	PRE IN1R 1.8 V • Turns ON when pin 17 is grounded. • A bias resistor (2.2 kΩ) must be connected between pin 2 and pin 24 (V _{ref}) when no head is in use.
3	PRE IN1F 1.8 V • Turns ON when pin 17 is floating. • A bias resistor (2.2 kΩ) must be connected between pin 3 and pin 24 (V _{ref}) when no head is in use.
4	PRE NF1 1.8 V
5	PRE OUT1 1.8 V • Like pin 6, 10 kΩ load drivable.
6	SW OUT1 1.8V • Provides PRE AMP1 output when pin 8 is floating (PRE MUTE OFF)(equivalent to pin 5). • Disconnects from PRE AMP1 and sets R _{IN} ≥ 500 kΩ when pin 8 is at V _{CC} (PRE MUTE ON).
7	POWER IN1 1.8V • Input resistance R _{IN} ≐ 30 kΩ

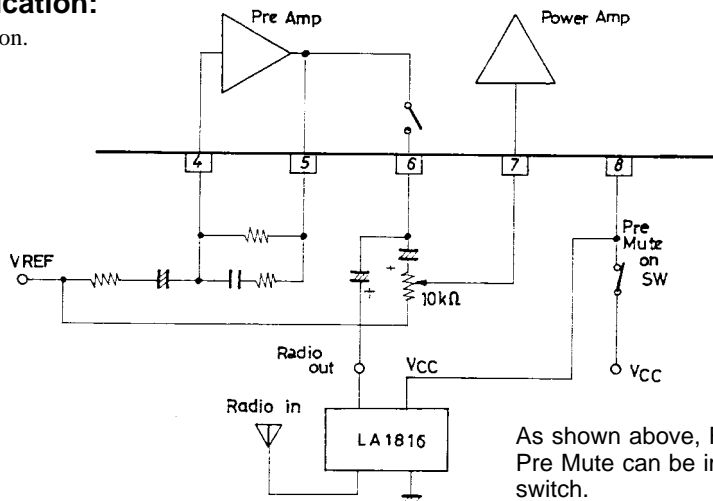
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Pin No.	Pin Function
8	PRE MUTE • When V_{CC} is applied, PRE MUTE ON. • MUTE ON conditions: $V_{8IN} \geq V_{CC} - 0.2$ V, inflow current $I_7 \div 60$ μ A (when $V_{CC} = 3$ V)
9	Ripple Filter REF 2.7 V ($C_7 = 2.2$ μ F to 33 μ F) • Ripple Filter, V_{ref} reference • The V_{ref} ripple rejection ratio worsens when C_7 is made smaller. • R_f is 55 dB for 22 μ F; 35 dB for 2.2 μ F.
10	Ripple Filter OUT 2.7 V • Ripple rejection ratio: R_f is 38 dB when $C_7 = 22$ μ F; 30 dB when $C_7 = 2.2$ μ F. • Outflow current I_7 max = 1 mA
11	V_{CC} 3.0 V
12	POWER GND
13	COMMON 1.2 V
14	POWER OUT1 1.2 V • CH1 output.
15	POWER OUT2 1.2 V • CH2 output
16	POWER MUTE 0.7 V ($C_{10} = 1.0$ μ F to 4.7 μ F) • When connected to GND: POWER MUTE ON. • MUTE ON conditions: $V_{16} \leq 0.3$ V, outflow current $I_{16} \div 2.5$ μ A. • C_{10} can be used to control MUTE TIME. • When $C_{10} = 2.2$ μ F, $V_{CC} = 3.0$ V 0.7 sec.
17	FWD/REV SW ($C_{11} \leq 0.47$ μ F) • When connected to GND, PRE IN1R (pin 2) and IN2R (pin 23) turn on. • When floating, PRE IN1F (pin 3) and IN2F (pin 22) turn on. • C_{11} and R_7 are intended for smoothing at the time of switching. • REV condition: $V_{17} \leq 0.2$ V.
18	POWER IN2 1.8 V • Input resistance $R_{IN} \div 30$ k Ω
19	SW OUT2 1.8 V • Provides PRE AMP2 when pin 8 is floating (PRE MUTE OFF) (equivalent to pin 20). • Disconnects from PRE AMP2 and $R_{IN} \geq 500$ k Ω when pin 8 is V_{CC} (PRE MUTE ON).
20	PRE OUT2 1.8 V • Like pin 19, 10 k Ω load drivable.
21	PRE NF2 1.8V
22	PRE IN2F 1.8 V • Turns on when pin 17 is floating. • A bias resistor (2.2 k Ω) must be connected between pin 22 and pin 24 (V_{ref}) when no head is in use.
23	PRE IN2R 1.8 V • Turns on when pin 17 is connected to GND. • A bias resistor (2.2 k Ω) must be connected between pin 23 and pin 24 (V_{ref}) when no head is in use.
24	V_{ref} 1.8 V • The reference voltage is set to $3/5 \times V_{CC}$. Because V_{ref} AMP ($r_O \div 10$ Ω) is built in, C_{17} can be made smaller (1 μ F). • Inflow/outflow current $I_{24} = \pm 500$ μ A available.

Sample Application:

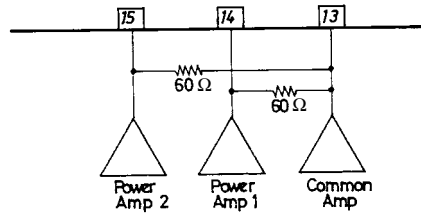
Radio set application.



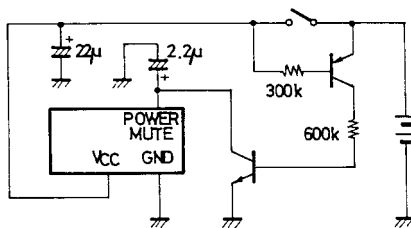
As shown above, Radio on and Pre Mute can be implemented with one-circuit switch.

IC Usage Notes

1. The power amplifier outputs and the common amplifier output are connected through resistors of about 60 Ω. The resistors are for common amplifier oscillation blocking.



2. The preamplifier muting function isolates the preamplifier outputs from SW OUT. The preamplifier is on even when the preamplifier muting is on.
3. If transient noise is noticeable when the power supply is turned off, add the external circuit described below. Transient noise when the power is turned off can be improved by rapidly applying the power amplifier muting.



Unit (resistance: Ω, capacitance: F)

However, the standby current I_{ST} flows even when the power switch is off

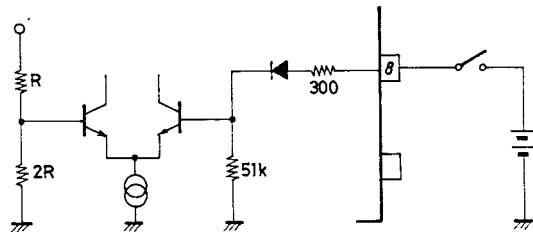
$$I_{ST} = (V_{CC} - V_{BE})/600 \text{ k}\Omega$$

When $V_{CC} = 3.0 \text{ V}$

$$I_{ST} = (3.0 - 0.6)/600 \text{ k}\Omega \div 4 \mu\text{A}$$

4. Internal equivalent circuit for each SW pin.

• Pre-mute

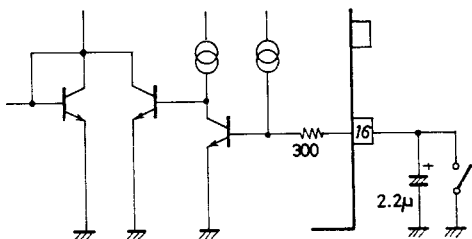


Unit (resistance: Ω)

MUTE ON condition : $V_{8IN} \geq V_{CC} - 0.2 \text{ V}$

Inflow current : $I_8 \div 60 \mu\text{A}$ (when $V_{CC} = 3.0 \text{ V}$)

• Power mute

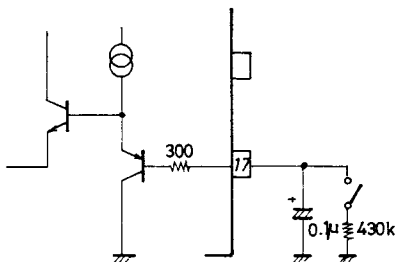


Unit (resistance: Ω, capacitance: F)

MUTE ON condition : $V_{16} \leq 0.3 \text{ V}$

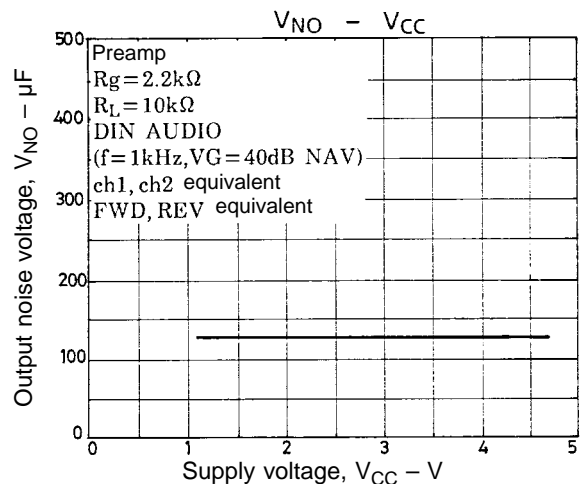
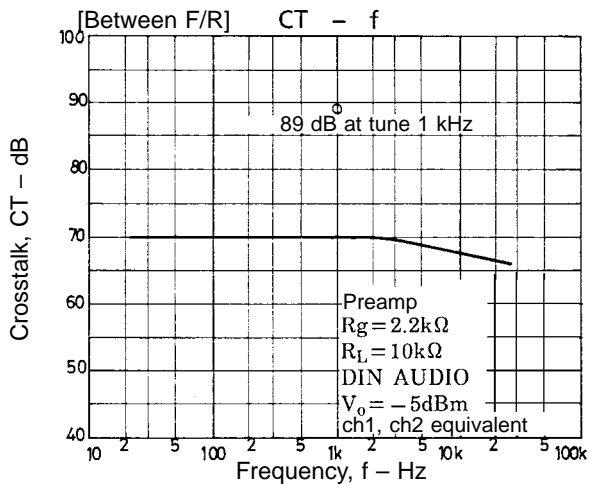
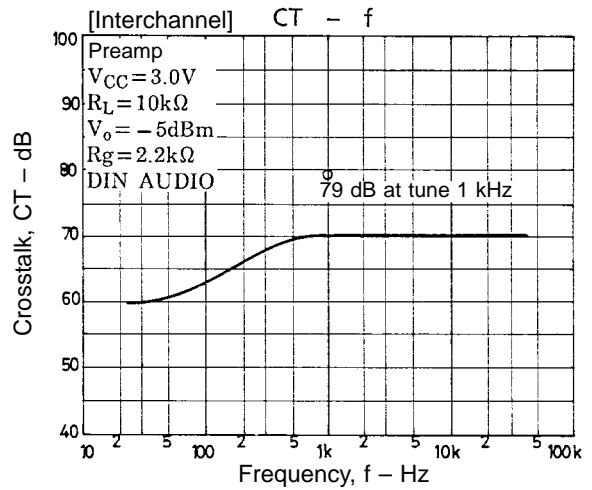
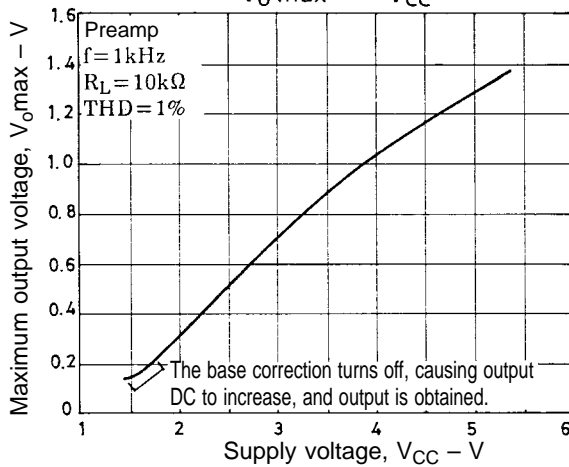
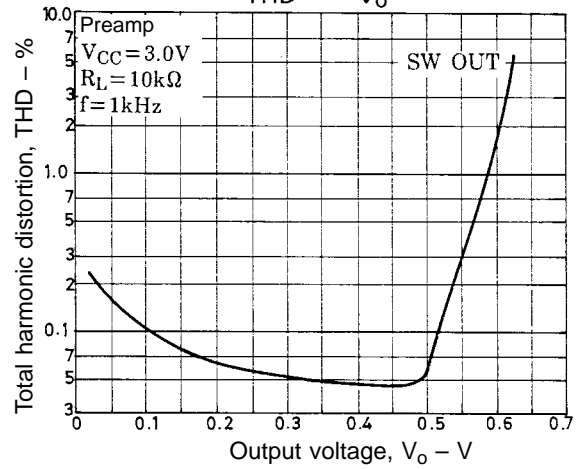
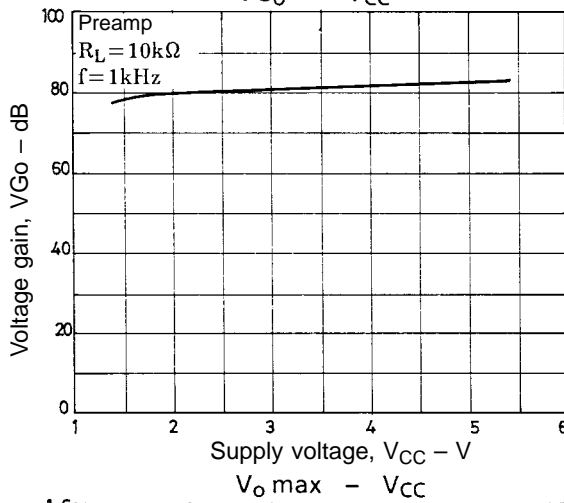
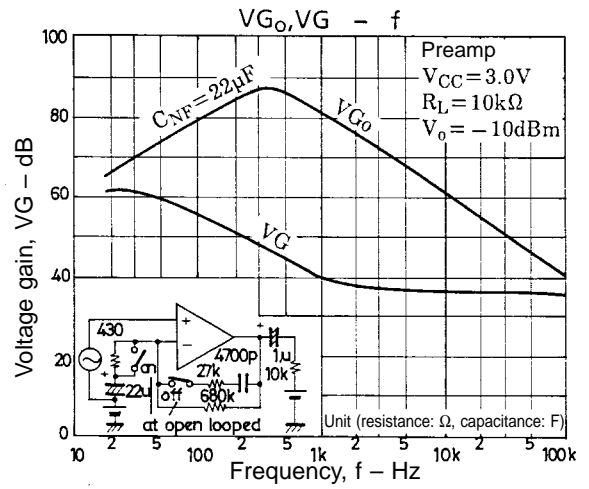
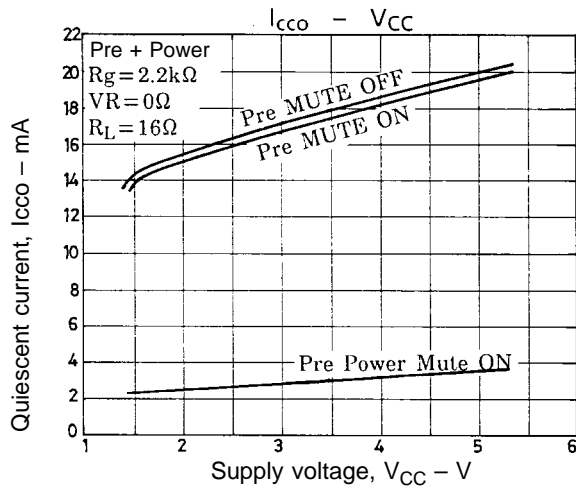
Outflow current : $I_{16} \div 2.5 \mu\text{A}$

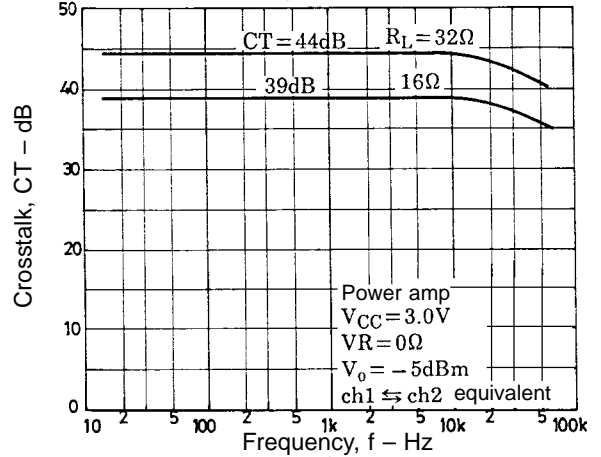
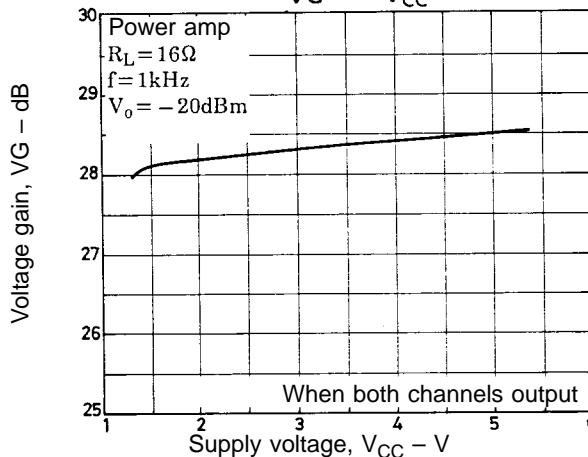
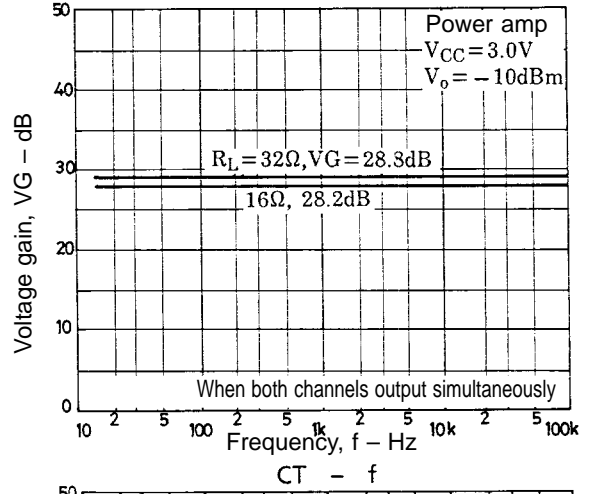
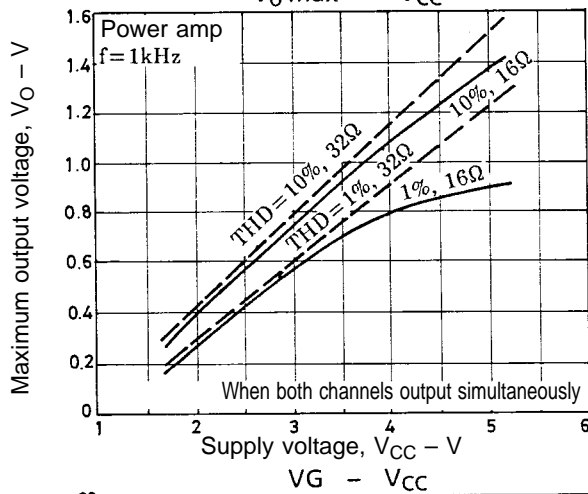
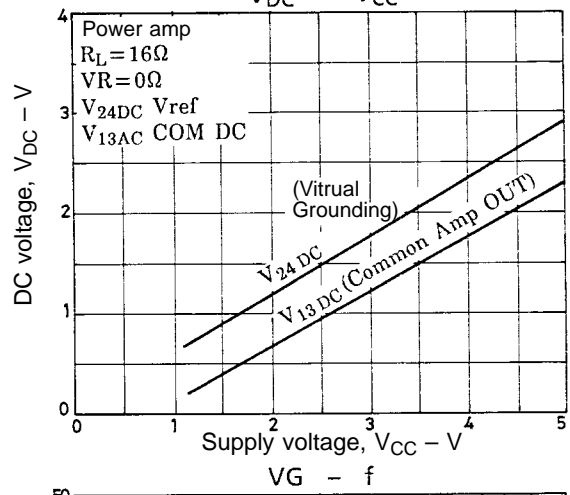
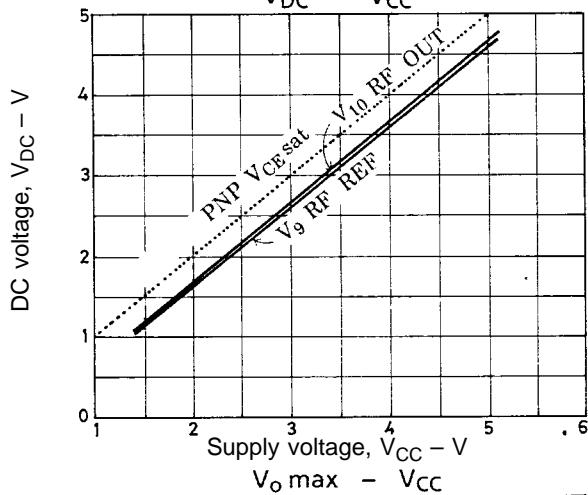
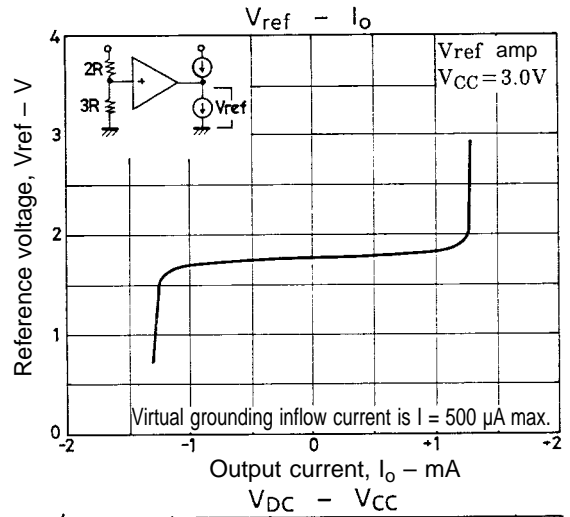
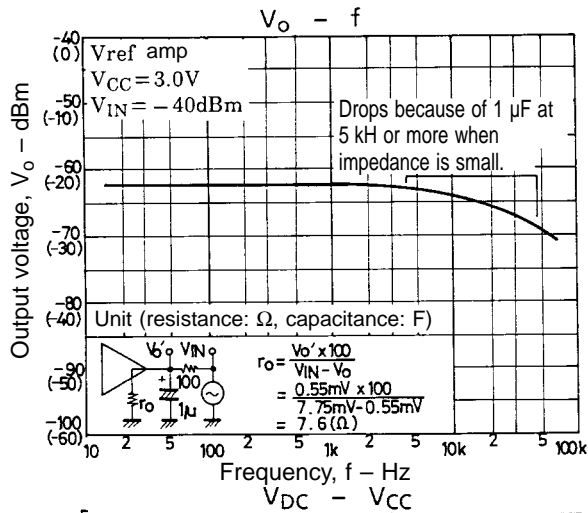
• F/R SW

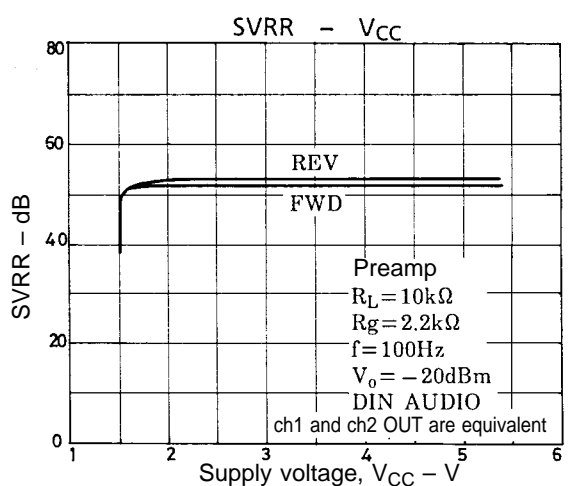
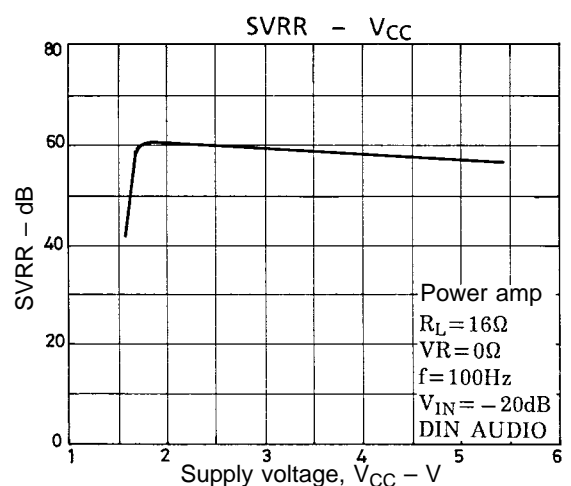
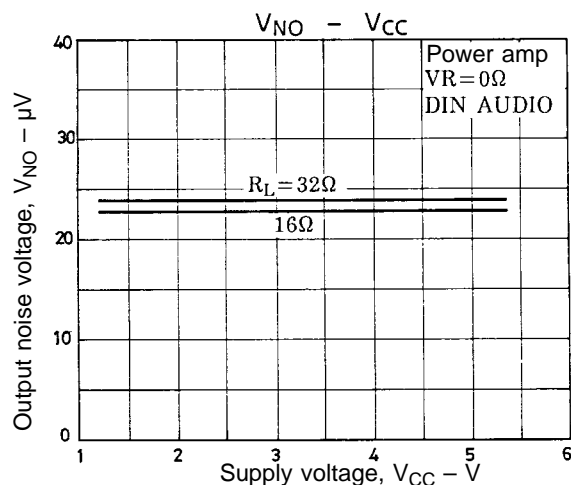
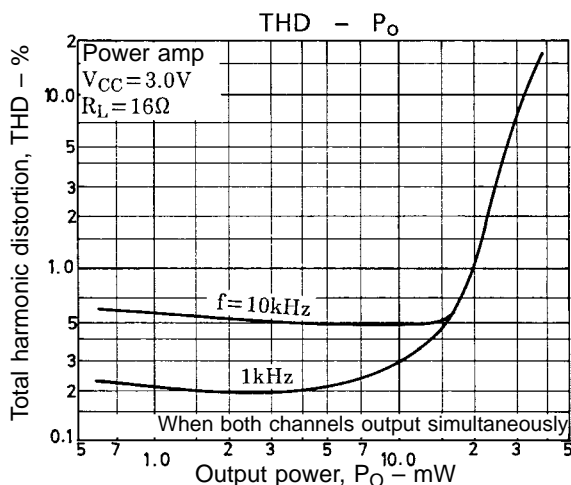
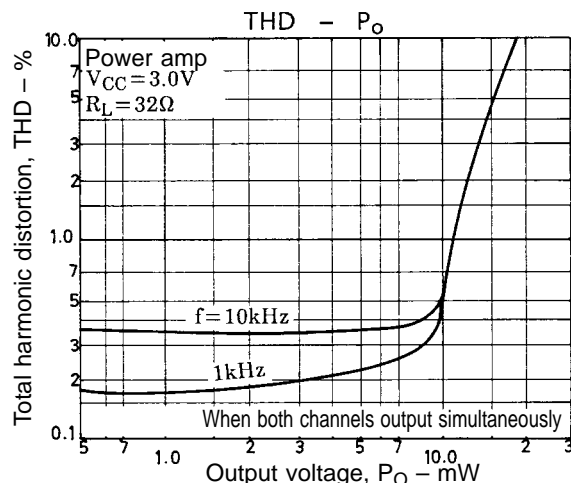
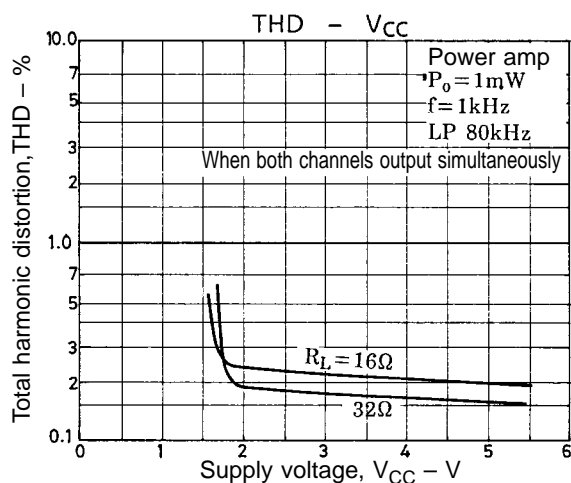


Unit (resistance: Ω, capacitance: F)

REV condition : $V_{17} \leq 0.2 \text{ V}$







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